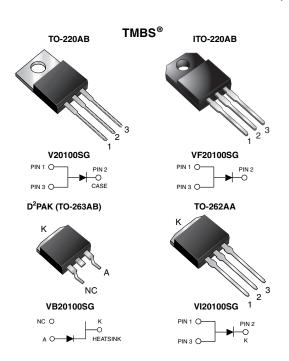


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High Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.50 \text{ V}$ at $I_F = 5 \text{ A}$



LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS					
I _{F(AV)}	20 A				
V_{RRM}	100 V				
I _{FSM}	150 A				
V_F at $I_F = 20 A$	0.75 V				
T _J max.	150 °C				
Package	TO-220AC, ITO-220AC, D ² PAK (TO-263AB), TO-262AA				
Circuit configuration	Single				

FEATURES

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses
- High efficiency operation

· Low thermal resistance



- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB, ITO-220AB, and TO-262AA package)
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, D 2 PAK (TO-263AB), and TO-262AA

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	V20100SG	VF20100SG	VB20100SG	VI20100SG	UNIT	
Maximum repetitive peak reverse voltage	V_{RRM}	100				V	
Maximum average forward rectified current (fig. 1)	I _{F(AV)}	20				Α	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	150				Α	
Non-repetitive avalanche energy at T _J = 25 °C, L = 60 mH	E _{AS}	150				mJ	
Peak repetitive reverse current at $t_p = 2 \mu s$, 1 kHz, $T_J = 38 ^{\circ}\text{C} \pm 2 ^{\circ}\text{C}$	I _{RRM}	1.0				Α	
Voltage rate of change (rated V _R)	dV/dt	10 000			V/µs		
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V _{AC}	1500			V		
Operating junction and storage temperature range	T _J , T _{STG}	-40 to +150				°C	

V20100SG, VF20100SG, VB20100SG, VI20100SG

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)								
PARAMETER	TEST CO	TEST CONDITIONS		TYP.	MAX.	UNIT		
Breakdown voltage	$I_R = 10 \text{ mA}$	T _A = 25 °C	V _{BR}	105 (minimum)	-	V		
Instantaneous forward voltage	I _F = 5 A		- V _F ⁽¹⁾	0.55	-	V		
	I _F = 10 A	T _A = 25 °C		0.66	-			
	I _F = 20 A			0.91	1.07			
	I _F = 5 A	T _A = 125 °C		0.50	-			
	I _F = 10 A			0.59	-			
	I _F = 20 A			0.75	0.82			
Reverse current	V _R = 70 V	T _A = 25 °C	I _R ⁽²⁾	15	-	μΑ		
	V _R = 70 V	T _A = 125 °C		6	-	mA		
	V _R = 100 V	T _A = 25 °C		60	350	μΑ		
	v _R = 100 v	T _A = 125 °C		13	25	mA		

Notes

⁽²⁾ Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	V20100SG	VF20100SG	VB20100SG	VI20100SG	UNIT	
Typical thermal resistance	$R_{\theta JC}$	2.2	4.0	2.2	2.2	°C/W	

ORDERING INFORMATION (Example)								
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
TO-220AB	V20100SG-E3/4W	1.88	4W	50/tube	Tube			
ITO-220AB	VF20100SG-E3/4W	1.74	4W	50/tube	Tube			
D ² PAK (TO-263AB)	VB20100SG-E3/4W	1.37	4W	50/tube	Tube			
D ² PAK (TO-263AB)	VB20100SG-E3/8W	1.37	8W	800/reel	Tape and reel			
TO-262AA	VI20100SG-E3/4W	1.45	4W	50/tube	Tube			

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

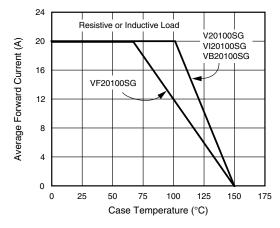


Fig. 1 - Maximum Forward Current Derating Curve

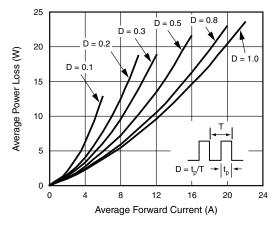


Fig. 2 - Forward Power Loss Characteristics

 $^{^{(1)}\,}$ Pulse test: 300 μs pulse width, 1 % duty cycle



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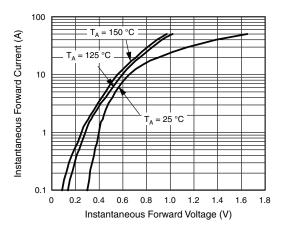


Fig. 3 - Typical Instantaneous Forward Characteristics

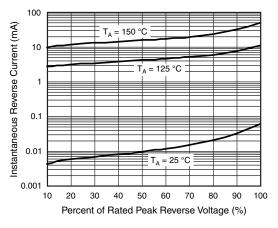


Fig. 4 - Typical Reverse Characteristics

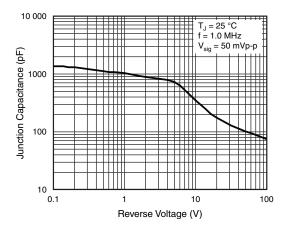


Fig. 5 - Typical Junction Capacitance

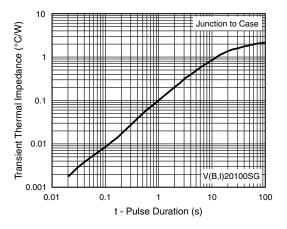


Fig. 6 - Typical Transient Thermal Impedance

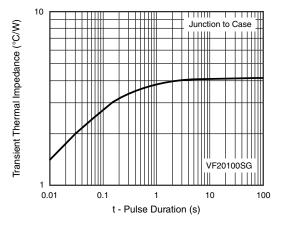
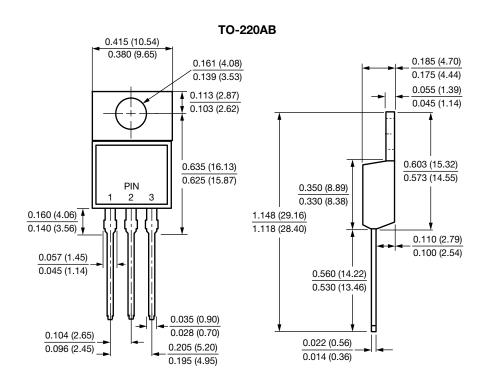


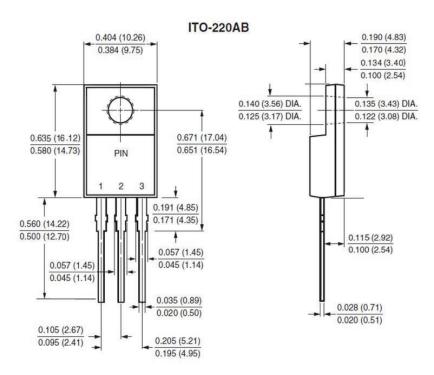
Fig. 7 - Typical Transient Thermal Impedance



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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

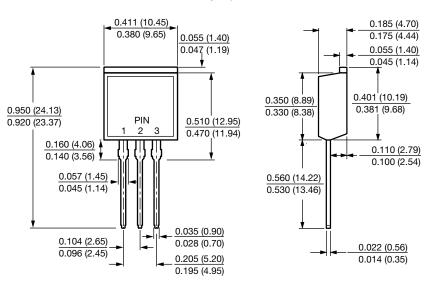


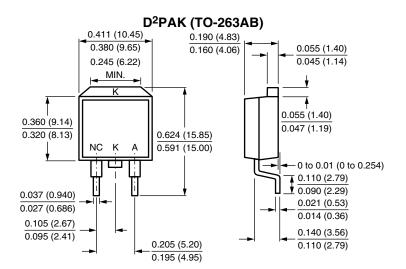




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TO-262AA





0.42 (10.66) MIN. 0.670 (17.02) 0.591 (15.00) 0.08 (2.032) MIN. 0.105 (2.67) 0.095 (2.41)



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